Circuit Quantum Electrodynamics with Semiconductor Quantum Dots

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CIRCUIT AND CAVITY QUANTUM ELECTRODYNAMICS erc

SEVENTH FRAMEWORK PROGRAMME

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Science and Technology

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Circuit QED with Quantum Dots: Motivation

Interconnect the worlds of semiconductor and superconductor based quantum circuits

Spin qubits in quantum dots



Science 309, 2180 (2005)

Circuit quantum electrodynamics



Nature 431, 162 (2004)

Attractive Features of Cavity/Circuit QED



... basic approach in circuits:

coherent quantum mechanics with individual photons and qubits ...



What is this good for?



- Isolate quantum system (QS) from its environment
- Maintain addressability of QS
- Read out the state of QS
- Couple QSs to each other
- Convert state of stationary QS into mobile photon

Cavity QED with Superconducting Circuits





coherent interaction of photons with quantum two-level systems ...

J. M. Raimond *et al., Rev. Mod. Phys.* 73, 565 (2001) S. Haroche & J. Raimond, *OUP Oxford* (2006) J. Ye., H. J. Kimble, H. Katori, *Science* 320, 1734 (2008)

Features:

- strong coupling in solid state sys.
- 'easy' to fabricate and integrate

Research directions:

- quantum optics
- quantum information
- hybrid quantum systems

A. Blais, *et al., PRA* 69, 062320 (2004) A. Wallraff *et al., Nature (London)* 431, 162 (2004) R. J. Schoelkopf, S. M. Girvin, *Nature (London)* 451, 664 (2008)

Quantum Optics



Strong Coherent Coupling Chiorescu *et al., Nature* 431, 159 (2004) Wallraff *et al., Nature* 431, 162 (2004) Schuster *et al., Nature* 445, 515 (2007)

Root n Nonlinearities Fink *et al., Nature* 454, 315 (2008) Deppe *et al., Nat. Phys.* 4, 686 (2008) Bishop *et al., Nat. Phys.* 5, 105 (2009)





Microwave Fock and Cat States Hofheinz *et al., Nature* 454, 310 (2008) Hofheinz *et al., Nature* 459, 546 (2009) Kirchmair *et al., Nature* 495, 205 (2013) Vlastakis *et al., Science* 342, 607 (2013)



Eidgenössische Technische Hochschule Zürich Swiss Federal Institute of Technology Zurich Parametric Amplification & Squeezing Castellanos-Beltran *et al., Nat. Phys.* 4, 928 (2008) Abdo *et al., PRX* 3, 031001 (2013)

> Waveguide QED – Qubit Interactions in Free Space Astafiev *et al., Science* 327, 840 (2010) van Loo *et al., Science* 342, 1494 (2013)



Quantum Computation

Teleportation L. Steffen *et al., Natur*e 500, 319 (2013)

Circuit QED Architecture A. Blais et al., *PRA* 69, 062320 (2004) A. Wallraff *et al., Nature* 431, 162 (2004) M. Sillanpaa *et al., Nature* 449, 438 (2007) H. Majer *et al., Nature* 449, 443 (2007) M. Mariantoni *et al., Science* 334, 61 (2011) R. Barends *et al., Nature* 508, 500 (2014)



Deutsch & Grover Algorithm, Toffoli Gate

L. DiCarlo *et al., Nature* 460, 240 (2009) L. DiCarlo *et al., Nature* 467, 574 (2010) A. Fedorov *et al., Nature* 481, 170 (2012)

Error Correction & Logical Qubits M. Reed *et al., Nature* 481, 382 (2012) Corcoles et al., *Nat. Com.* 6, 6979 (2015) Ristè et al., *Nat. Com.* 6, 6983 (2015) Kelly et al., *Nature* 519, 66-69 (2015)

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Quantum Simulation

Digital simulation of exchange, Heisenberg, Ising spin models



Salathe *et al., PRX* 5, 021027 (2015)

Quantum simulation of correlated systems with variational Ansatz based on MPS



Eichler et al., Phys. Rev. X 5, 041044 (2015)

Analog simulations with cavity and/or qubit arrays Houck *et al.*, *Nat Phys.* 8, 292 (2012)



Barends *et al., Nat. Com.* 6, 7654 (2015)



Hybrid Systems with Superconducting Circuits

Spin Ensembles: e.g. NV centers D. Schuster *et al., PRL* 105, 140501 (2010) Y. Kubo *et al., PRL* 105, 140502 (2010)



CNT, Gate Defined 2DEG, or nanowire Quantum Dots M. Delbecq *et al., PRL* 107, 256804 (2011) T. Frey *et al., PRL* 108, 046807 (2012) K. Petersson *et al., Nature* 490, 380 (2013)



Rydberg Atoms 5. Hogan*et al., PRL* 108, 063004 (2012)

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Polar Molecules, Rydberg, BEC P. Rabl *et a*l, *PRL* 97, 033003 (2006) A. Andre *et a*l, *Nat. Phys.* 2, 636 (2006) D. Petrosyan *et a*l, *PRL* 100, 170501 (2008) J. Verdu *et a*l, *PRL* 103, 043603 (2009)



Nano-Mechanics J. Teufel *et al., Nature* 475, 359 (2011) X. Zhou *et al., Nat. Phys.* 9, 179(2013)



... and many more

Circuit QED with Quantum Dots: Motivation

Interconnect the worlds of semiconductor and superconductor based quantum circuits

Spin qubits in quantum dots



Science 309, 2180 (2005)

Circuit quantum electrodynamics



Nature 431, 162 (2004)

Potential benefits:

- realize interfaces between quantum systems
- allow for coherent control while isolating from environment
- achieve long distance coupling
- implement alternative measurement/read-out schemes
- explore correlations between charge transport and radiation emission

Experiments with Propagating Quantum Microwaves

Single photon sources and their anti-bunching

d

Houck *et al., Nature* 449, 328 (2007) Bozyigit *et al.,* Nat. Phys 7, 154 (2011) Lang *et al., PRL* 107, 073601 (2011)

Full state tomography and Wigner functions of propagating photons

Eichler et al., PRL 106, 220503 (2011)



Eidgenössische Technische Hochschule Zürich Swiss Federal Institute of Technology Zurich Creation and characterization of entanglement of qubits with propagating photons



Eichler *et al., PRL* 109*, 240501* (2012) Eichler *et al., PRA* 86*,* 032106 (2012)

Hong-Ou-Mandel: Two-photon interference incl. msrmnt of coherences at microwave freq.



Hybrid Quantum Dot / Circuit QED Device



Hybrid Quantum Dot / Circuit QED Device



T. Frey et al., PRL 108, 046807 (2012)

Semiconductor Circuit QED Hybrid Systems

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InAs nano-wire quantum dots:

K. D. Petersson et al., *Nature* 490, 380-383 (2012) Liu *et al., PRL* 113, 036801 (2014) Liu *et al., Science* 347, 285-287 (2015)

> Carbon nanotube quantum dots: M. Delbecq et al., *PRL* 107, 256804 (2011) J. Viennot et al., *Science* 349, 408 (2015)

a

GaAs quantum dots:



H. Toida et al., *PRL* 110, 066802 (2013) A. Wallraff et al., *PRL* 111, 249701 (2013)



Double Dot Charge Stability Diagram



Double Dot Current and Resonator Transmission

Transport measurements:

Charging diagrams

dot properties:

- many electron regime
- large charging energy
- consider two-level approx.





Double Dot Current and Resonator Transmission

Transport measurements:

Charging diagrams

dot properties:

- many electron regime
- large charging energy
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T. Frey *et al., PRL* 108, 046807 (2012)

Double Dot Current and Resonator Transmission

Transport measurements:

Charging diagrams

dot properties:

- many electron regime
- large charging energy
- consider two-level approx.

Resonator transmission:





- systematic changes in transmission amplitude and phase
- equivalent charging diagrams ...
- ... but different physical origin of signal







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Model of the Coupled Resonator–Dot System



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Regimes of Resonant Circuit/Cavity QED



Eidgenössische Technische Hochschule Zürich Swiss Federal Institute of Technology Zurich bad (or fast) cavity limit (κ > g > γ)



Resonator/Double-Dot Interaction



T. Frey et al., PRL 108, 046807 (2012)

Quantitative Evaluation of Dipole-Coupling



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Single-Electron Regime

Optimized gate geometry for single electron regime of DQD coupled to resonator

Expectation: improved coherence



However:

- same large dephasing $(\gamma >> g)$
- similar dephasing rates in many (all?) other hybrid DQD experiments independent of material



dl_{opc}/dV_{LPG}(nS) (a) -410 (0,2) -420 (1,2) -430 2.2 (0,1) -440 V_{RPG}(mV) -10 (1,1)-450 (2,1) -15 -460 (0,0) -20 -470 -480 -25 (1,0) (2,0)-490 -30 -500 -440 -420 -400 -380 460 V_{LPG}(mV) (b) A/A_o -43 (1,2) 1.00 (2,2) 0.96 (2,1)(2,0) 0.92 -380-390

Quantum Dot Bias Regimes

tunnel coupling between dots



- tunnel coupling (t) similar to resonator frequency
- coupling to leads (Γ) small

tunnel coupling between lead and dot



- coupling to leads (Γ) similar to resonator frequency
- tunnel coupling (t) small

tunnel coupling to both leads



 coupling to leads (Γ) similar tunnel coupling (t) similar to resonator frequency

Investigation of tunnel coupling to leads at GHz frequencies: T. Frey *et al.*, *PRB* 86, 115303 (2012)





Eidgenössische Technische Hochschule Zürich Swiss Federal Institute of Technology Zurich T. Frey *et al., PRB* 86, 115303 (2012)

Improved Cavity-Coupled GaAs Double Quantum Dot



Device design:

- iterated from previous versions T. Frey *et al.*, *PRL* 108, 046807 (2012)
- cavity frequency ν ~ 6.85 GHz (28 $\mu eV)$
- QD charging energies $E_c \sim 200 \text{ GHz} (1 \text{ meV})$

improved charge coherence properties

- $\gamma_{\phi} \sim 200 \text{ MHz}$
- previously several GHz

likely affected by:

- reduced overlap between gates and 2DEG
- different wafer material
- improved filtering

Device Characterization

dispersive resonator shift versus QD bias:



parameters:

- constant cavity coupling strength $g \sim$ 13 MHz
- adjustable inter-dot coupling $t \sim 1$ to 10 GHz
- adjustable inter-dot detuning δ ~ 0 to 100's GHz
- approx. energy relaxation rate $\gamma_1 \sim 100 \text{ MHz}$
- dephasing rate $\gamma_{\phi} \sim 0.2$ to 1.2 GHz (depending on bias)
- approx. # charges (*n,m*) ~ 10

A. Stockklauser et al., Phys. Rev. Lett. 115, 046802 (2015)

Radiation Emission Experiments: Motivation

- explore radiation emission from semiconductor nanostructure
- investigate correlations between charge transport and radiation emission
- characterize inelastic tunneling processes

Approach:

- voltage bias DQD
- adjust DQD energy levels
- detect emitted radiation

Use techniques known from circuit QED:

- sensitive parametric amplifiers
- quadrature amplitude measurements
- power measurements
- correlation function measurements



A. Stockklauser et al., Phys. Rev. Lett. 115, 046802 (2015)

Related work on radiation emission and micro-maser action Liu *et al., PRL* 113, 036801 (2014), *Science* 347, 285-287 (2015)

Parametric Amplifier



JPD amplifier: implementation



finger array of capacitor SQUIDs

Features:

- Arrays with M SQUIDs to control nonlinearity: $U \sim E_c/M^2$
- asymmetric SQUIDs -> homogeneous coupling to external flux

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JPD amplifier: implementation



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JPD amplifier: non-degenerate operation





JPD amplifier: degenerate operation





Control



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Sensing Small Electromagnetic Signals

Radiation Emission at Finite Bias



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measured source/drain current at bias voltage $V_{SD} = -200 \ \mu V$ (~ 50 GHz)

• observation of finite bias triangles

measured power spectral density (PSD) as a function of inter-dot detuning δ

- line-width given by cavity $\kappa \sim 3.3 \text{ MHz}$
- power is strongly δ -dependent

A. Stockklauser et al., Phys. Rev. Lett. 115, 046802 (2015)

Integrated Emitted Power vs. Inter-Dot Detuning

Observations:

- weak emission over broad range in δ proportional to bias current
- emission rate: 10⁻⁴ photons per electron
 - two pronounced maxima in emission symmetric around $\delta = o$
 - emission rate increased 10x



Emission Resonances vs. Inter-Dot Tunnel Coupling



- inter-dot tunneling t-independent background emission (subtracted)
- maxima in emission symmetric about inter-dot detuning δ = 0
- emission gaussian in detuning δ (FWHM ~ 1.5 GHz)
- large (approx. δ -independent) emission for forward bias δ > 0
- small (δ -dependent) emission for reverse bias δ < 0

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Tunnel-Coupling Dependence of Emission Maxima





Interpretation:

• Inter-dot detuning δ_r resonance with cavity depends on tunnel coupling *2t*

$$\delta = \pm \sqrt{(h\nu_r)^2 - (2t)^2}$$

• good agreement with observed bias at emission maxima

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Scaling of Forward and Reverse Bias Emission with 2t







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Dependence of Emission on Coupling to Leads

 Investigation of width of emission resonances in dependence on broadening of quantum dot levels due to coupling to leads





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A. Stockklauser *et al.*, ETH Zurich *unpublished* (2016)

Dependence of Emission on Coupling to Leads

- Symmetric configuration $\Gamma_{\rm L} = \Gamma_{\rm R}$, constant t, $V_{\rm SD}$
- Elastic current $I = I_{el} \propto \Gamma_R$
- Resonance width increases with Γ_L , Γ_R



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A. Stockklauser *et al.*, ETH Zurich *unpublished* (2016)

Dependence of Emission on Coupling to Leads



- Approximately linear increase with the current
- Expected level broadening: $\Gamma = \Gamma_{\rm R} + \tilde{\gamma}$
- $\gamma/2\pi \le 250$ MHz in the entire range of source-drain coupling
- $I = I_{el} \text{ converted to tunnel}$ rate $\Gamma_{\rm L} = \Gamma_{\rm R}$
- Emission linewidth and qubit level broadening proportional to tunnel rates to leads

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A. Stockklauser *et al.*, ETH Zurich *unpublished* (2016)

Summary

- Performed photon emission measurements from semiconductor DQD
- Used circuit QED measurement techniques for characterization of emission
- Obtained good understanding of emission process

Outlook

- Investigate radiation emission using correlation function measurements
- Work towards strong coupling to charge (overcome 100 MHz scale dephasing rate)
- Use resonator as a coupling bus in semiconductor-based QIP
- Explore benefits of circuit QED in semiconductor structures

A. Stockklauser *et al., Phys. Rev. Lett.* 115, 046802 (2015)
J. Basset *et al., Phys. Rev. B* 88, 125312 (2013)
T. Frey *et al., Phys. Rev. B* 86, 115303 (2012)
T. Frey *et al., Phys. Rev. Lett.* 108, 046807 (2012)



The ETH Zurich Quantum Device Lab

incl. undergrad and summer students

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